

550V Super-Junction Power MOSFET

FEATURES

- Very low FOM $R_{DS(on)} \times Q_g$
- 100% avalanche tested
- RoHS compliant

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

TO-220 GD S	TO-220F GDS	TO-251 G D S
RoHS	TO-252	G° S°

Device Marking and Package Information					
Device	TPA55R2K1C	TPP55R2K1C	TPU55R2K1C	TPD55R2K1C	
Package	TO-220F	TO-220	TO-251	TO-252	
Marking 55R2K1C 55R2K1C 55R2K1C 55R2K1C					

Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted

Absolute maximum Ratings $T_c = 23$ C, unless otherwise noted					
Parameter		Symbol	Value		11
		Symbol	TO-220,TO-251,TO-252	TO-220F	Unit
Drain-Source Voltage (V _{GS} = 0V)		V _{DSS}	550		V
Continuous Drain Current	continuous Drain Current		1.6		A
Pulsed Drain Current	(note1) I _{DM}		4.8		A
Gate-Source Voltage		V _{GSS}	±30		V
Single Pulse Avalanche Energy	(note2)	E _{AS}	1.25		mJ
Avalanche Current (note1)		I _{AR}	0.5		A
Repetitive Avalanche Energy (note1)		E _{AR}	0.04		mJ
Power Dissipation (T _C = 25°C)		P _D	16.7	8.1	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55~+150		°C

Thermal Resistance					
Peremeter	Symbol	Value		11-14	
Parameter	Symbol	TO-220,TO-251,TO-252	TO-220F	Unit	
Thermal Resistance, Junction-to-Case	R _{thJC}	7.5	15.4		
Thermal Resistance, Junction-to-Ambient	R _{thJA}	62	80	K/W	



Specifications $T_J = 25^{\circ}C$, ur	less othe	rwise noted					
Parameter	Symbol Test Conditions		Value			Unit	
rarameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	550			V	
Zara Cata Valtaga Drain Current	1	$V_{DS} = 550V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 550V, V _{GS} = 0V, T _J = 150°C			100	μA	
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 30V$			±100	nA	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.5		4.0	V	
Drain-Source On-Resistance (Note3)	$R_{DS(on)}$	V _{GS} = 10V, I _D = 0.8A		1.9	2.1	Ω	
Forward Transconductance (Note3)	g _{fs}	V _{DS} = 10V, I _D = 0.8A		1.4		S	
Dynamic		•					
Input Capacitance	C _{iss}	$\gamma = 0 \gamma$		147		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 50V,$		27			
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		5			
Total Gate Charge	Q _g			4.4		nC	
Gate-Source Charge	Q _{gs}	$V_{DD} = 400V, I_{D} = 1.6A, V_{GS} = 10V$		0.7			
Gate-Drain Charge	Q_{gd}			2.5			
Turn-on Delay Time	t _{d(on)}			48			
Turn-on Rise Time	t _r	V _{DD} = 400V, I _D = 1.6A,		16		ns	
Turn-off Delay Time	t _{d(off)}	$R_{G} = 25\Omega$		32			
Turn-off Fall Time	t _f			22			
Drain-Source Body Diode Characteri	stics						
Continuous Body Diode Current	I _s	T 0500			1.6		
Pulsed Diode Forward Current	I _{SM}	$T_{\rm C} = 25^{\circ}{\rm C}$			6.4	A	
Body Diode Voltage	V _{SD}	T _J = 25°C, I _{SD} = 1.6A, V _{GS} = 0V		0.9	1.2	V	
Reverse Recovery Time	t _{rr}			104		ns	
Reverse Recovery Charge	Q _{rr}	$V_R = 400V, I_F = I_S,$ $di_F/dt = 100A/\mu s$		0.4		μC	
Peak Reverse Recovery Current	I _{rrm}			4.1		А	

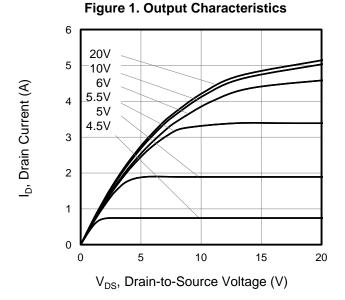
Notes

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2. $I_{AS} = 0.5A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 1%

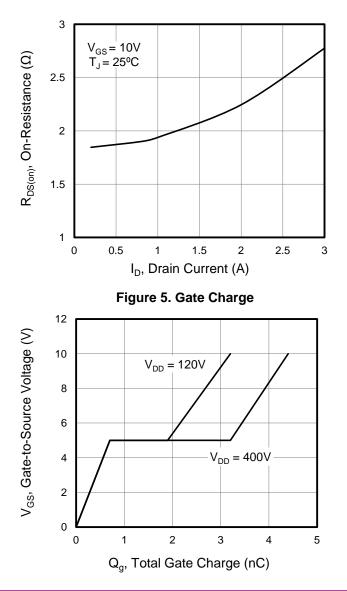




Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted







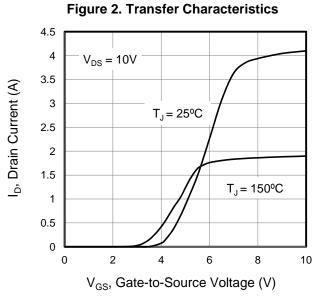


Figure 4. Capacitance

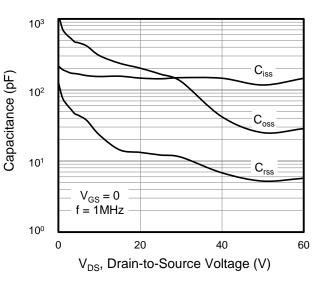
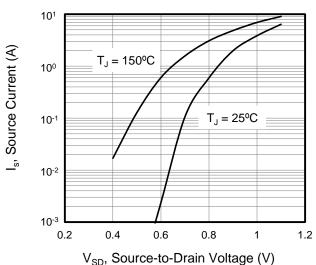


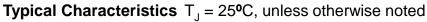
Figure 6. Body Diode Forward Voltage

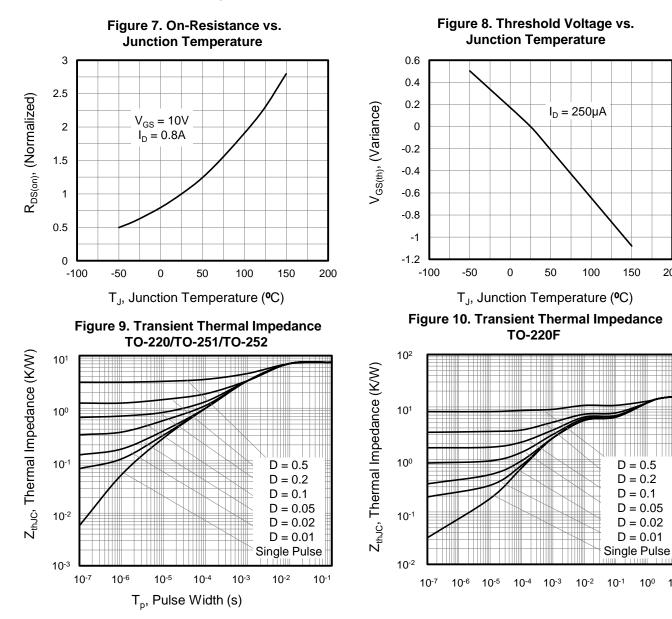


TPA55R2K1C,TPP55R2K1C,TPU55R2K1C,TPD55R2K1C



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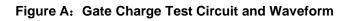


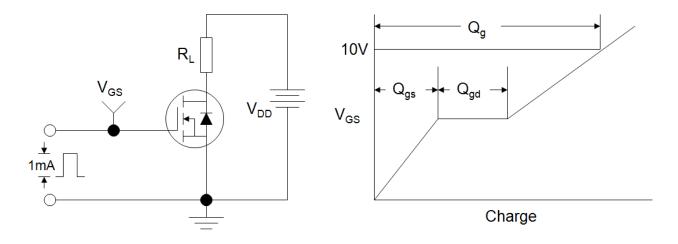


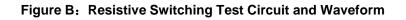
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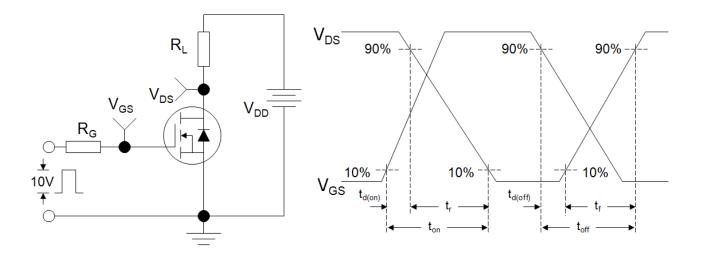
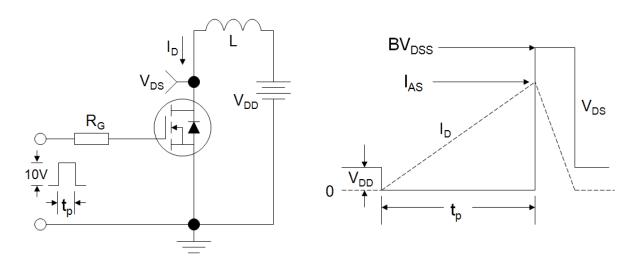
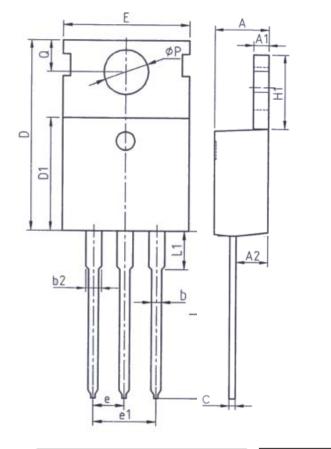


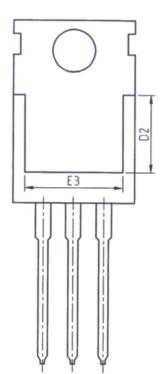
Figure C: Unclamped Inductive Switching Test Circuit and Waveform





TO-220

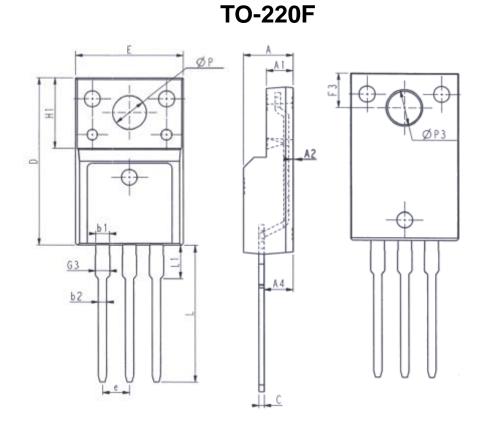




Unit: mm				
Symbol	Min.	Max.		
Α	4.37	4.77		
A1	1.25	1.45		
A2	2. 20	2.60		
b	0.70	0.95		
b2	1.17	1.47		
c	0.40	0.65		
D	15.10	16. 10		
D1	8.80	9.40		
D2	5.50	-		

Unit: mm			
Symbol	Min. Max.		
E	9.70	10. 30	
E3	7.00	-	
e	2.54	BSC	
e1	5. 08	BBSC	
H1	6. 25	6.85	
L	12.75	13.80	
L1	I	3. 40	
Р	3.40 3.80		
Q	2.60	3.00	

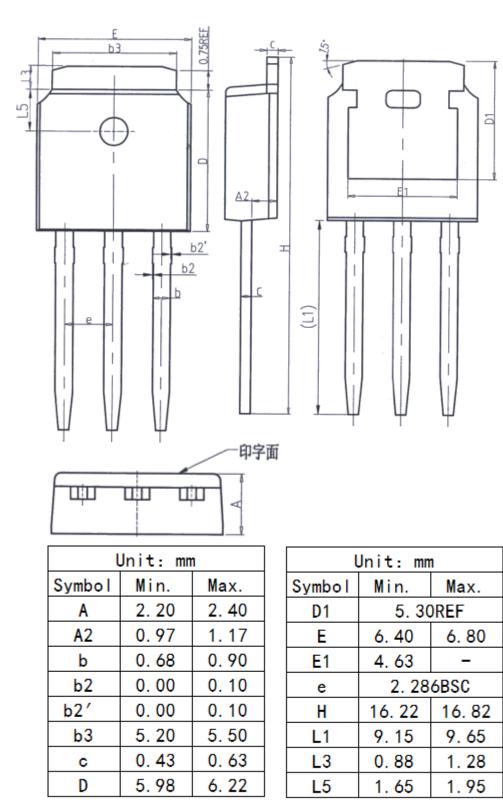




Unit: mm		l	Jnit: mm	ı	
Symbol	Min.	Max.	Symbol	Min.	Max.
E	9.96	10.36	L	12. 68	13. 28
Α	4. 50	4.90	L1	2.93	3.13
A1	2.34	2.74	Р	3.03	3. 38
A2	0.30	0.60	P3	3. 15	3.65
A4	2.56	2.96	F3	3.15	3. 45
с	0.40	0.65	G3	1.25	1.55
D	15. 57	16. 17	b1	1.18	1.43
H1	6. 70REF		b2	0.70	0.95
e	2. 54BSC				

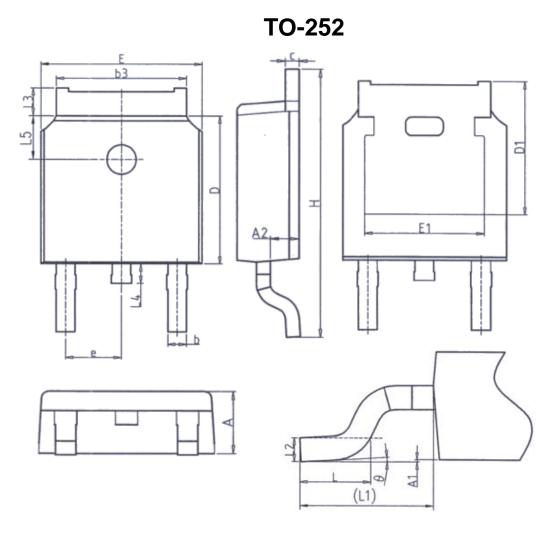
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TO-251





Unit: mm				
Symbol	Min.	Max.		
Α	2.20	2.40		
A1	0.00	0.20		
A2	0.97	1.17		
b	0.68	0.90		
b3	5.20	5.50		
с	0.43	0.63		
D	5.98	6. 22		
D1	5. 30REF			
E	6.40	6.80		
E1	4.63	-		

Unit: mm			
Symbol	Min.	Max.	
е	2. 28	6BSC	
Н	9.40	10.50	
L	1.38	1.75	
L1	2.90REF		
L2	0, 51	BSC	
L3	0.88	1.28	
L4	_	1.00	
L5	1.65	1.95	
θ	0°	8°	



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